

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7443	(ONO (oxide near nitride near oxide)) with ((isolat\$3 oxide) near (layer film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/02/11 15:23
L2	387	1 and (pn adj junction)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/02/11 15:24
L3	110	2 and SOI	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/02/11 15:25
L4	78	3 and silicide	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/02/11 16:05
L5	3	((("5466960") or ("5079182"))).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2005/02/11 16:05
S1	0	1996-0002744	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:03
S2	0	"19960002744"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:03
S3	161	"0002744"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:03
S4	27	"0002744" and "1996"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:05
S5	0	"0002744" and (isolat\$3 near film)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:06

S6	49	method near form\$3 near element near isolat\$3 near film	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:25
S7	4863	257/51,347,377,382,384,412,413.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:26
S8	37	257/51,347,377,382,384,412,413.ccls. and (((isolat\$3 oxide) near (layer film)) with (pn adj junction))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:38
S9	357243	"257"/\$.ccls. "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:36
S10	0	257/51,347,377,382,384,412,413.ccls. and (ONO with ((isolat\$3 oxide) near (layer film)) with (pn adj junction))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:36
S11	2	("257"/\$.ccls. "438"/\$.ccls.) and (ONO with ((isolat\$3 oxide) near (layer film)) with (pn adj junction))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:49
S12	703	("257"/\$.ccls. "438"/\$.ccls.) and (((isolat\$3 oxide) near (layer film)) with (pn adj junction))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:38
S13	52	((("257"/\$.ccls. "438"/\$.ccls.) and (((isolat\$3 oxide) near (layer film)) with (pn adj junction)))) and (ONO (oxide near nitride near oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:50
S14	3	(ONO (oxide near nitride near oxide)) with ((isolat\$3 oxide) near (layer film)) with (pn adj junction)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/02/11 15:23
S15	1075	((isolat\$3 oxide) near (layer film)) with (pn adj junction)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/02/11 15:24

S16	73	((isolat\$3 oxide) near (layer film)) with (pn adj junction)) and (ONO (oxide near nitride near oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/10/16 13:51
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